

# Single Thyristor (MAGN-A-PAK Block Power Module), 500 A



**MAGN-A-PAK Block** 

PRIMARY CHARACTERISTICS						
I <sub>T(AV)</sub> 500 A						
Type	Modules - thyristor, standard					
Package	MAGN-A-PAK block					

#### **FEATURES**

- · Electrically isolated base plate
- 3000 V<sub>BMS</sub> isolating voltage
- Industrial standard package
- · Simplified mechanical designs, rapid assembly
- High surge capability
- Large creepage distances
- UL approved file E78996
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912"><u>www.vishav.com/doc?99912</u></a>

#### **APPLICATIONS**

- Battery chargers
- Welders
- Power converters
- Alternators

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
V <sub>DRM</sub> /V <sub>RRM</sub>		800	V				
I <sub>T(AV)</sub>	76 °C	500					
I <sub>T(RMS)</sub>		785	1				
1	50 Hz	14 000	A				
I <sub>TSM</sub>	60 Hz	14 658					
124	50 Hz	980	kA <sup>2</sup> s				
60 Hz		894	KA-S				
$I^2\sqrt{t}$		9800	kA²√s				
TJ	Range	-40 to +130	°C				

#### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS									
TYPE NUMBER	V <sub>RRM</sub> /V <sub>DRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> /V <sub>DSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> /I <sub>DRM</sub> AT 130 °C mA						
VS-VSKS500/08PbF	800	900	80						



ON-STATE CONDUCTION							
PARAMETER	SYMBOL		VALUES	UNITS			
Maximum average on-state current	I <sub>T(AV)</sub>	180° conduction	on half sine wave		500	Α	
at case temperature	T(AV)	100 conduction	on hair sine wave		76	°C	
Maximum RMS on-state current	I <sub>T(RMS)</sub>	As AC switch			785		
		t = 10 ms	No voltage		16 646		
Maximum peak, one-cycle on-state, non-repetitive		t = 8.3 ms	reapplied		17 430	А	
surge current	I <sub>TSM</sub>	t = 10 ms	100 % V <sub>RRM</sub>		14 000		
		t = 8.3 ms	reapplied	Sine half wave, initial	14 658		
		t = 10 ms	No voltage	$T_J = T_J$ maximum	1385	- kA <sup>2</sup> s	
NA. 1 121 for for the	l <sup>2</sup> t	t = 8.3 ms	reapplied		1265		
Maximum I <sup>2</sup> t for fusing		t = 10 ms	100 % V <sub>RRM</sub>		894		
		t = 8.3 ms	reapplied		894		
Maximum I <sup>2</sup> √t for fusing	I <sup>2</sup> √t	t = 0.1 ms to 1	0 ms, no voltage	reapplied	1385	kA²√s	
Low level value of threshold voltage	V <sub>T(TO)1</sub>	(16.7 % x π x l	$T(AV) < I < \pi \times I_{T(AV)}$	ŋ), T <sub>J</sub> maximum	0.6839	V	
High level value of threshold voltage	V <sub>T(TO)2</sub>	$(I > \pi \times I_{T(AV)}), T$	0.7598	] v			
Low level value on-state slope resistance	r <sub>t1</sub>	(16.7 % x π x l	0.393	mΩ			
High level value on-state slope resistance	r <sub>t2</sub>	$(I > \pi \times I_{T(AV)}), T_J$ maximum 0.389					
Maximum on-state voltage drop	$V_{TM}$	$T_J = 25 ^{\circ}\text{C}, I_{pk} = 500 \text{A}$ 1.1				V	

SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Typical delay time	t <sub>d</sub>	Gate current 1 A, $dl_g/dt = 1$ A/ $\mu$ s, $V_d = 0.67$ % $V_{DRM}$ , $T_J = 25$ °C, $l_t = 400$ A	1.3	
Typical turn-off time	t <sub>q</sub>	$I_{TM}=750~A,~T_J=T_J~maximum,~dI/dt=60~A/\mu s,~V_R=50~V,\\ dV/dt=20~V/\mu s,~Gate~0~V~100~\Omega,~t_p=500~\mu s$	200	μs

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum linear to 67 % rated $V_{DRM}$	500	V/µs
Maximum peak reverse and off-state leakage current	I <sub>DRM</sub> , I <sub>RRM</sub>	$T_J = T_J$ maximum, rated $V_{DRM}/V_{RRM}$ applied	80	mA
RMS insulation voltage	V <sub>INS</sub>	50 Hz, circuit to base, all terminal shorted, $t = 1 \text{ s}$	3000	V



TRIGGERING					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum peak gate power	P <sub>GM</sub>	$T_J = T_J$ maximum, $t_p \le 5$ ms	10.0	w	
Maximum average gate power	P <sub>G(AV)</sub>	$T_J = T_J$ maximum, $f = 50$ Hz, $d\% = 50$	2.0	VV	
Maximum peak positive gate current	I <sub>GM</sub>	$T_J = T_J$ maximum, $t_p \le 5$ ms	3.0	Α	
Maximum required DC gate voltage to trigger	$V_{GT}$		3	V	
Maximum required DC gate current to trigger	I <sub>GT</sub>	T <sub>J</sub> = 25 °C Anode supply: 12 V resistive load	200	A	
Maximum holding current	I <sub>H</sub>		600	mA	
Maximum peak positive gate voltage	+V <sub>GM</sub>	T. T. magazina ma t. < 5 mag	20	V	
Maximum peak negative gate voltage	-V <sub>GM</sub>	$T_J = T_J$ maximum, $t_p \le 5$ ms	5.0	V	
DC gate voltage not to trigger	$V_{GD}$	T <sub>J</sub> = T <sub>J</sub> maximum Maximum gate current/voltage not to trigger	0.30	V	
DC gate current not to trigger	I <sub>GD</sub>	is the maximum value which will not trigger any unit with rated V <sub>DRM</sub> anode to cathode applied	10	mA	
Maximum non-repetitive rate of rise of turned-on current	dl/dt	Gate drive 20 V, 20 $\Omega$ , $t_r \le 1~\mu s$ $T_J = T_J~maximum,~anode~voltage \le 80~\% V_{DRM},~l_t = 400~A$	1000	A/µs	

THERMAL AND MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction operating and storage temperature range			-40 to +130	°C				
Maximum thermal resistance, junction to case per junction		DC operation	0.08	- K/W				
Maximum thermal resistance, case to heatsink per module	R <sub>thCS</sub>	Mounting surface smooth, flat and greased 0.035						
Mounting MAGN-A-PAK block to heatsink		A mounting compound is recommended	6 to 8					
torque ± 10 % busbar to MAGN-A-PAK block		and the torque should be rechecked after a period of 3 h to allow for the spread of the compound. Lubricated threads.	12 to 15	Nm				
Approximate weight			430	g				
Approximate weight			15.3	OZ.				
Case style			MAGN-A-PAI	K block				

△R CONDUCTION PER JUNCTION											
DEVICES		SINUSOII AT	DAL CONI			RECTANGULAR CONDUCTION AT T <sub>J</sub> MAXIMUM				UNITS	
	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	
VS-VSKS500	0.013	0.0148	0.018	0.026	0.044	0.082	0.0142	0.019	0.027	0.044	K/W

### Note

Table shows the increment of thermal resistance R<sub>thJC</sub> when devices operate at different conduction angles than DC

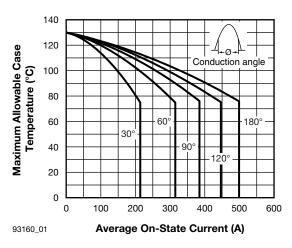


Fig. 1 - Current Rating Characteristics

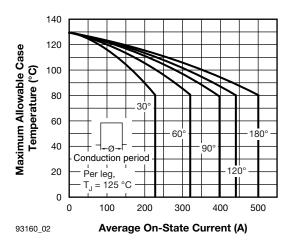


Fig. 2 - Current Rating Characteristics

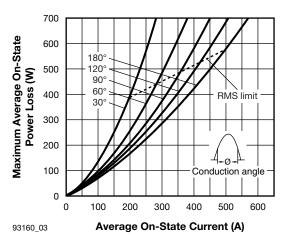


Fig. 3 - On-State Power Loss Characteristics

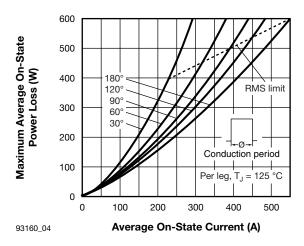


Fig. 4 - On-State Power Loss Characteristics

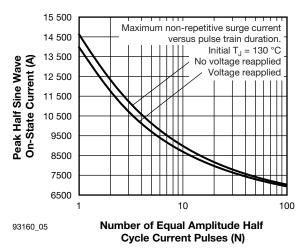


Fig. 5 - Maximum Non-Repetitive Surge Current

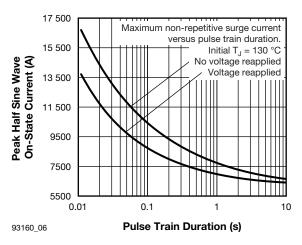


Fig. 6 - Maximum Non-Repetitive Surge Current

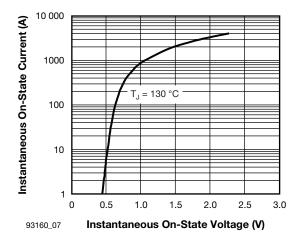


Fig. 7 - On-State Voltage Drop Characteristics

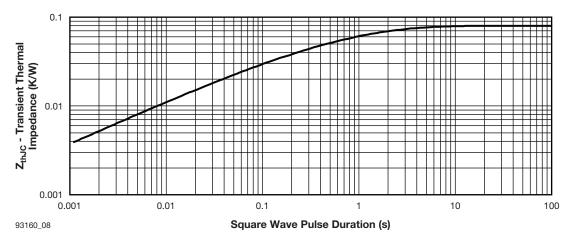
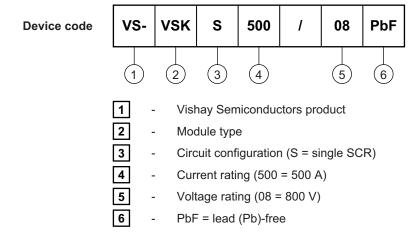


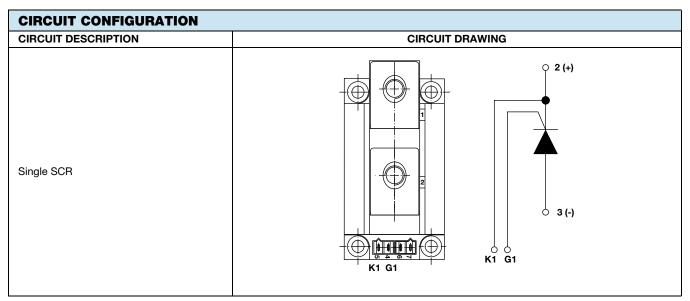
Fig. 8 - Thermal Impedance Z<sub>thJC</sub> Characteristics

#### **ORDERING INFORMATION TABLE**







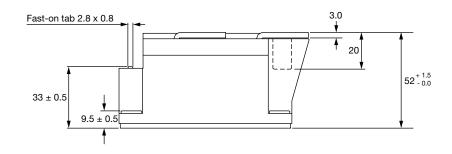


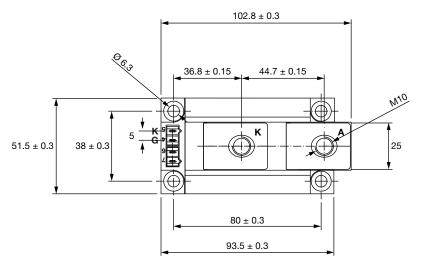
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95379				



# **Thyristor MAP Block**

## **DIMENSIONS** in millimeters





#### Notes

- Dimensions are nominal
- Full engineering drawings are available on request



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